Powered-off Protection, 6 Ω, 1.8 V to 5.5 V, SPDT Analog Switch (2:1 Multiplexer)

DESCRIPTION

The DG9411E is a high performance single-pole, double-throw (SPDT) analog switch designed for 1.8 V to 5.5 V operation with a single power rail.

Fabricated with high density CMOS technology, the device achieves low on resistance of 6 Ω and switch off capacitance of 7 pF at a 5 V power supply and low power consumption, and fast switching speeds.

The DG9411E can handle both analog and digital signals and permits signals with amplitudes of up to V+ to be transmitted in either direction. Its control logic inputs can go over V+ up to 5.5 V. It features break before make switching performance.

A powered-off protection circuit is built into the switch to prevent an abnormal current flow from COM pin to V+ during the power-down condition. Each output pin can withstand greater than 7 kV (human body model).

Operation temperature is specified from -40 °C to +85 °C. The DG9411E is available in the compact SC-70-6L package.

FEATURES

- Low switch on-resistance (6 Ω)
- 1.8 V to 5.5 V single supply operation
- Powered-off protection
- Control logic inputs can go over V+ up to 5.5 V
- Low parasitic capacitance, 7 pF at switch off
- Low charge injection, 1 pC
- Break before make switching
- Latch-up performance exceeds 200 mA per JESD 78
- ESD tested
  - 7000 V human body model (JS-001)
  - 1000 V charge device model (JS-002)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

Pb-free Available

RoHS* Available

APPLICATIONS

- Battery powered devices
- Smartphones and tablets
- Consumer and computing
- Portable instrumentation
- Medical equipment

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

SC-70

Top view

Device marking

● H7
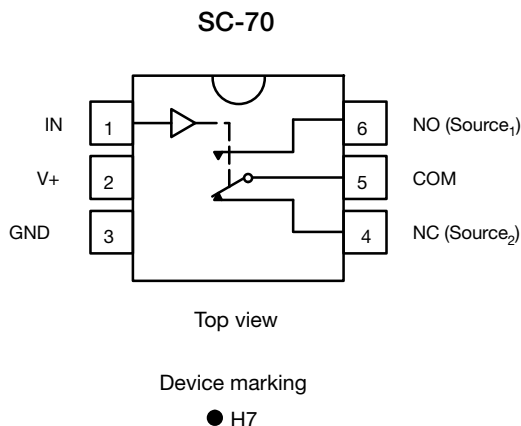
TRUTH TABLE

LOGIC	NC	NO
0	On	Off
1	Off	On

Notes

- Logic "0" ≤ 0.8 V
- Logic "1" ≥ 2.4 V

ORDERING INFORMATION

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +85 °C	SC-70-6	DG9411EDL-T1-GE3

For technical questions, contact: analogswitchtechsupport@vishay.com

ABSOLUTE MAXIMUM RATINGS

PARAMETER		LIMIT	UNIT
V+, COM, NC, NO, IN reference to GND		-0.3 to 6	V
Continuous current (any terminal)		± 50	mA
Peak current (pulsed at 1 ms, 10 % duty cycle)		± 200	
Storage temperature		-65 to +150	°C
Power dissipation (packages) [a]	6-pin SC-70 [b]	250	mW
ESD / HBM	JS-001	7000	V
ESD / CDM	JS-002	1000	
Latch up	Per JESD78 with 1.5 x voltage clamp	200	mA

Notes
a. All leads welded or soldered to PC board
b. Derate 3.1 mW/°C above 70 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS (V+ = 5 V)

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, ± 10 % V_{IN} = 0.8 V or 2.4 V [e]	TEMP.[a]	LIMITS -40 °C to +85 °C			UNIT
				MIN. [b]	TYP. [c]	MAX. [b]	
Analog Switch							
Analog signal range [d]	V_{NO}, V_{NC} V_{COM}		Full	0	-	V+	V
Drain-source on-resistance [d]	$R_{DS(on)}$	V+ = 4.5 V, V_{COM} = 3 V, I_{NO}, I_{NC} = 10 mA	Room	-	6	9	Ω
			Full	-	8	11	
$R_{DS(on)}$ flatness [d]	$R_{DS(on)}$ flatness	V+ = 5 V, V_{COM} = 1.5 V, 3.5 V, I_{NO}, I_{NC} = 10 mA	Room	-	0.4	-	
$R_{DS(on)}$ match [d]	$\Delta R_{DS(on)}$	V+ = 4.5 V, V_{COM} = 3 V, I_{NO}, I_{NC} = 10 mA	Room	-	0.04	0.2	
Switch-off leakage current [f]	$I_{NO(off)}$, $I_{NC(off)}$	V+ = 5.5 V, V_{NO}, V_{NC} = 1 V / 4.5 V, V_{COM} = 4.5 V / 1 V	Room	-1.5	-	1.5	nA
			Full	-4	-	4	
	$I_{COM(off)}$		Room	-1	-	1	
			Full	-4	-	4	
Channel-on leakage current [f]	$I_{COM(on)}$	V+ = 5.5 V, V_{NO}, V_{NC} = V_{COM} = 1 V / 4.5 V	Room	-1	-	1	
			Full	-4	-	4	
Power-down leakage	I_{PD}	V+ = 0 V, V_{COM} = 5 V, NO/NC open, V_{IN} = GND	Full	-	-	2	µA
		V+ = 0 V, V_{NO}, V_{NC} = 5 V, COM open, V_{IN} = GND	Full	-	-	2	
Digital Control							
Input high voltage	V_{INH}		Full	2.4	-	-	V
Input low voltage	V_{INL}		Full	-	-	0.8	
Input capacitance [d]	C_{IN}		Full	-	6	-	pF
Input current	I_{INL} or I_{INH}	V_{IN} = 0 V or V+	Full	-1	-	1	µA
Dynamic Characteristics							
Turn-on time [d]	t_{ON}	V_{NO} or V_{NC} = 3 V, R_L = 300 Ω, C_L = 35 pF	Room	-	10	30	ns
			Full	-	-	32	
Turn-off time [d]	t_{OFF}		Room	-	8	24	
			Full	-	-	26	
Break-before-make time [d]	t_{BBM}		Room	1	-	-	
Charge injection [d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, V_{NO}, V_{NC} = 0 V, R_{GEN} = 0 Ω	Room	-	1	-	pC
Off-isolation [d]	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room	-	-78	-	dB
Crosstalk [d]	X_{TALK}		Room	-	-77	-	
NO, NC off capacitance [d]	$C_{NO(off)}$	V_{IN} = 0 V or V+, f = 1 MHz	Room	-	7	-	pF
	$C_{NC(off)}$		Room	-	7	-	
Channel-on capacitance [d]	C_{ON}		Room	-	13	-	
Power Supply							
Power supply current [d]	I+	V_{IN} = 0 V or V+	Full	-	0.004	1	µA

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SPECIFICATIONS (V+ = 3 V)

| PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, ± 10 % V_{IN} = 0.4 V or 2 V [e]	TEMP. [a]	LIMITS -40 °C to +85 °C			UNIT
				MIN. [b]	TYP. [c]	MAX. [b]	
Analog Switch							
Analog signal range [d]	V_{NO}, V_{NC} V_{COM}		Full	0	-	V+	V
Drain-source on-resistance [d]	$R_{DS(on)}$	V+ = 2.7 V, V_{COM} = 1.5 V, I_{NO}, I_{NC} = 10 mA	Room	-	13	22	Ω
			Full	-	15	24	
$R_{DS(on)}$ flatness [d]	$R_{DS(on)}$ flatness	V+ = 3 V, V_{COM} = 0 V to V+, I_{NO}, I_{NC} = 10 mA	Room	-	1.4	-	
$R_{DS(on)}$ match [d]	$\Delta R_{DS(on)}$	V+ = 2.7 V, V_{COM} = 1.5 V, I_{NO}, I_{NC} = 10 mA	Room	-	0.03	0.35	
Switch-off leakage current [f]	$I_{NO(off)}$, $I_{NC(off)}$	V+ = 3.3 V, V_{NO}, V_{NC} = 1 V / 3 V, V_{COM} = 3 V / 1 V	Room	-400	-	400	pA
			Full	-4	-	4	nA
	$I_{COM(off)}$		Room	-800	-	800	pA
			Full	-8	-	8	nA
Channel-on leakage current [f]	$I_{COM(on)}$	V+ = 3.3 V, V_{NO}, V_{NC} = V_{COM} = 1 V / 3 V	Room	-800	-	800	pA
			Full	-8	-	8	nA
Digital Control							
Input high voltage	V_{INH}		Full	2	-	-	V
Input low voltage	V_{INL}		Full	-	-	0.4	
Input capacitance [d]	C_{IN}		Full	-	6	-	pF
Input current	I_{INL} or I_{INH}	V_{IN} = 0 V or V+	Full	-1	-	1	µA
Dynamic Characteristics							
Turn-on time [d]	t_{ON}	V_{NO} or V_{NC} = 2 V, R_L = 300 Ω, C_L = 35 pF	Room	-	13	34	ns
			Full	-	-	37	
Turn-off time [d]	t_{OFF}		Room	-	9	20	
			Full	-	-	22	
Break-before-make time [d]	t_{BBM}		Room	1	-	-	
Charge injection [d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, V_{NO}, V_{NC} = 0 V, R_{GEN} = 0 Ω	Room	-	0.9	-	pC
Off-isolation [d]	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room	-	-78	-	dB
Crosstalk [d]	X_{TALK}		Room	-	-77	-	
NO, NC off capacitance [d]	$C_{NO(off)}$	V_{IN} = 0 V or V+, f = 1 MHz	Room	-	7	-	pF
	$C_{NC(off)}$		Room	-	7	-	
Channel-on capacitance [d]	C_{ON}		Room	-	14	-	
Power Supply							
Power supply current [d]	I+	V_{IN} = 0 V or V+	Full	-	0.002	1	µA

SPECIFICATIONS (V+ = 2.5 V)

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 2.5 V, ± 10 % V_{IN} = 0.4 V or 2 V [e]	TEMP. [a]	LIMITS -40 °C to +85 °C			UNIT
				MIN. [b]	TYP. [c]	MAX. [b]	
Analog Switch							
Analog signal range [d]	V_{NO}, V_{NC} V_{COM}		Full	0	-	V+	V
Drain-source on-resistance [d]	$R_{DS(on)}$	V+ = 2.2 V, V_{COM} = 1 V, I_{NO}, I_{NC} = 10 mA	Room	-	23	29.5	Ω
			Full [d]	-	24	30.5	
$R_{DS(on)}$ flatness [d]	$R_{DS(on)}$ flatness	V+ = 2.5 V, V_{COM} = 0 V to V+, I_{NO}, I_{NC} = 10 mA	Room	-	1.7	-	
$R_{DS(on)}$ match [d]	$\Delta R_{DS(on)}$	V+ = 2.2 V, V_{COM} = 1.2 V, I_{NO}, I_{NC} = 10 mA	Room	-	0.1	0.5	
Switch-off leakage current [f]	$I_{NO(off)}$, $I_{NC(off)}$	V+ = 2.7 V, V_{NO}, V_{NC} = 0.5 V / 1.5 V, V_{COM} = 1.5 V / 0.5 V	Room	-200	-	200	pA
			Full [d]	-3	-	3	nA
	$I_{COM(off)}$		Room	-200	-	200	pA
			Full [d]	-3	-	3	nA
Channel-on leakage current [f]	$I_{COM(on)}$	V+ = 2.7 V, V_{NO}, V_{NC} = V_{COM} = 0.5 V / 1.5 V	Room	-200	-	200	pA
			Full [d]	-3	-	3	nA
Digital Control							
Input high voltage	V_{INH}		Full	2	-	-	V
Input low voltage	V_{INL}		Full	-	-	0.4	
Input capacitance [d]	C_{IN}		Full	-	6	-	pF
Input current	I_{INL} or I_{INH}	V_{IN} = 0 V or V+	Full	-1	-	1	µA
Dynamic Characteristics							
Turn-on time [d]	t_{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 300 Ω, C_L = 35 pF	Room	-	16	36	ns
			Full [d]	-	-	38	
Turn-off time [d]	t_{OFF}		Room	-	10	19	
			Full	-	-	21	
Break-before-make time [d]	t_{BBM}		Room [d]	1	-	-	
Charge injection [d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, V_{NO}, V_{NC} = 0 V, R_{GEN} = 0 Ω	Room	-	0.9	-	pC
Off-isolation [d]	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room	-	-78	-	dB
Crosstalk [d]	X_{TALK}		Room	-	-77	-	
NO, NC off capacitance [d]	$C_{NO(off)}$	V_{IN} = 0 V or V+, f = 1 MHz	Room	-	7	-	pF
	$C_{NC(off)}$		Room	-	7	-	
Channel-on capacitance [d]	C_{ON}		Room	-	14	-	
Power Supply							
Power supply current [d]	I+	V_{IN} = 0 V or V+	Full	-	-	1	µA

SPECIFICATIONS (V+ = 2 V)

| PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 2 V, ± 10 % V_{IN} = 0.4 V or 1.6 V [e]	TEMP.[a]	LIMITS -40 °C to +85 °C MIN. [b]	TYP. [c]	MAX. [b]	UNIT
Analog Switch							
Analog signal range [d]	V_{NO}, V_{NC} V_{COM}		Full	0	-	V+	V
Drain-source on-resistance [d]	$R_{DS(on)}$	V+ = 1.8 V, V_{COM} = 1 V, I_{NO}, I_{NC} = 10 mA	Room	-	37	45	Ω
			Full [d]	-	36	47	
$R_{DS(on)}$ flatness [d]	$R_{DS(on)}$ flatness	V+ = 2 V, V_{COM} = 0 V to V+, I_{NO}, I_{NC} = 10 mA	Room	-	3	-	
$R_{DS(on)}$ match [d]	$\Delta R_{DS(on)}$	V+ = 1.8 V, V_{COM} = 1 V, I_{NO}, I_{NC} = 10 mA	Room	-	0.04	0.5	
Switch-off leakage current [f]	$I_{NO(off)}$, $I_{NC(off)}$	V+ = 2.2 V, V_{NO}, V_{NC} = 0.5 V / 1.5 V, V_{COM} = 1.5 V / 0.5 V	Room	-200	-	200	pA
			Full [d]	-3	-	3	nA
	$I_{COM(off)}$		Room	-200	-	200	pA
			Full [d]	-3	-	3	nA
Channel-on leakage current [f]	$I_{COM(on)}$	V+ = 2.2 V, V_{NO}, V_{NC} = V_{COM} = 0.5 V / 1.5 V	Room	-200	-	200	pA
			Full [d]	-3	-	3	nA
Digital Control							
Input high voltage	V_{INH}		Full	1.6	-	-	V
Input low voltage	V_{INL}		Full	-	-	0.4	
Input capacitance [d]	C_{IN}		Full	-	6	-	pF
Input current	I_{INL} or I_{INH}	V_{IN} = 0 V or V+	Full	-1	-	1	µA
Dynamic Characteristics							
Turn-on time [d]	t_{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 300 Ω, C_L = 35 pF	Room	-	21	40	ns
			Full [d]	-	-	42	
Turn-off time [d]	t_{OFF}		Room	-	13	20	
			Full [d]	-	-	21	
Break-before-make time [d]	t_{BBM}		Room	1	-	-	
Charge injection [d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, V_{NO}, V_{NC} = 0 V, R_{GEN} = 0 Ω	Room	-	0.8	-	pC
Off-isolation [d]	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room	-	-78	-	dB
Crosstalk [d]	X_{TALK}		Room	-	-77	-	
NO, NC off capacitance [d]	$C_{NO(off)}$	V_{IN} = 0 V or V+, f = 1 MHz	Room	-	7	-	pF
	$C_{NC(off)}$		Room	-	7	-	
Channel-on capacitance [d]	C_{ON}		Room	-	14	-	
Power Supply							
Power supply current [d]	I+	V_{IN} = 0 V or V+	Full	-	-	1	µA

Notes

a. Room = 25 °C, full = as determined by the operating suffix
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
c. Typical values are for design aid only, not guaranteed nor subject to production testing
d. Guarantee by design, nor subjected to production test
e. V_{IN} = input voltage to perform proper function
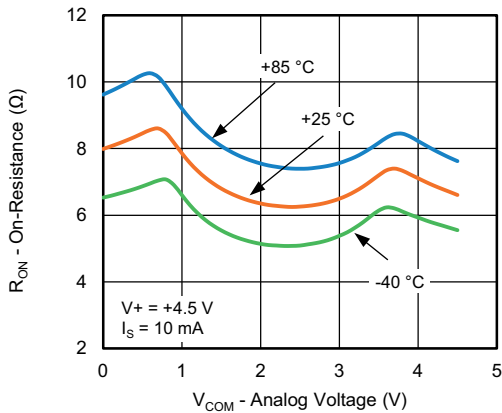f. Guaranteed by 5 V leakage testing, not production tested

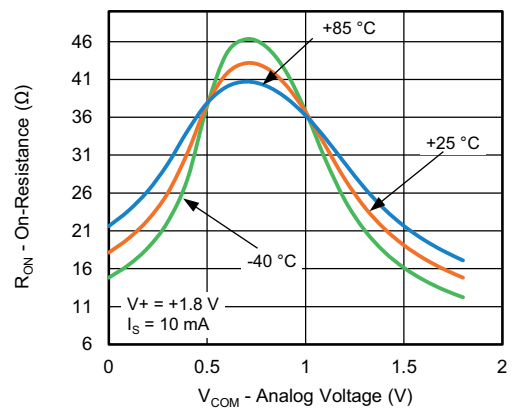## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)
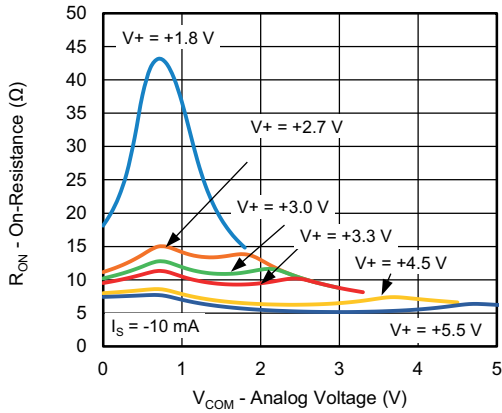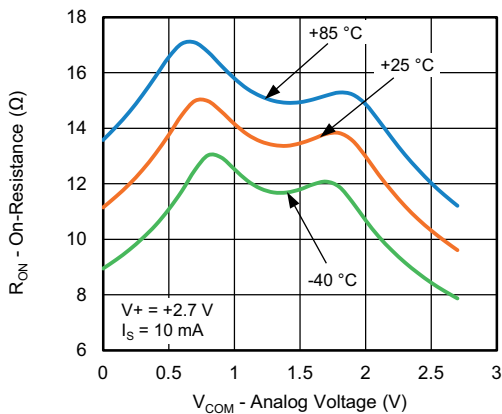

R$_{DS(on)}$ vs. V$_{COM}$ and Supply Voltage
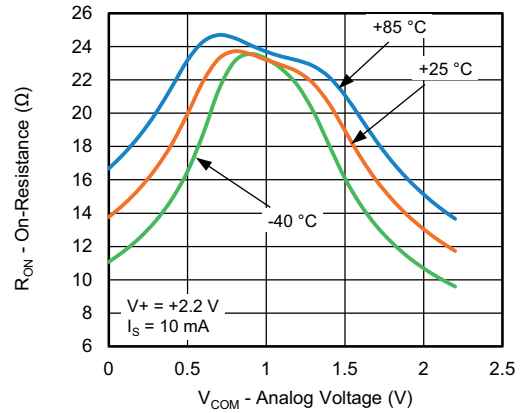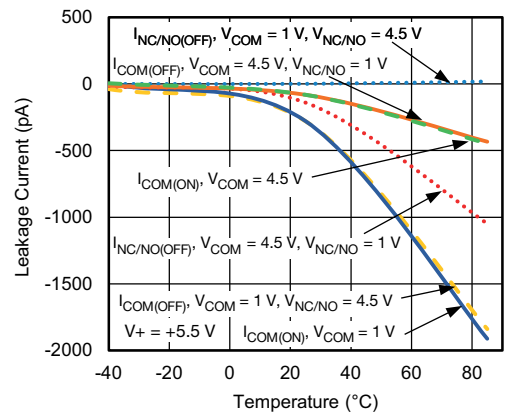

R$_{DS(on)}$ vs. Analog Voltage and Temperature

R$_{DS(on)}$ vs. Analog Voltage and Temperature
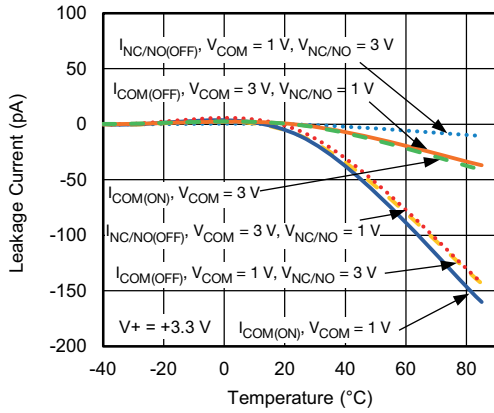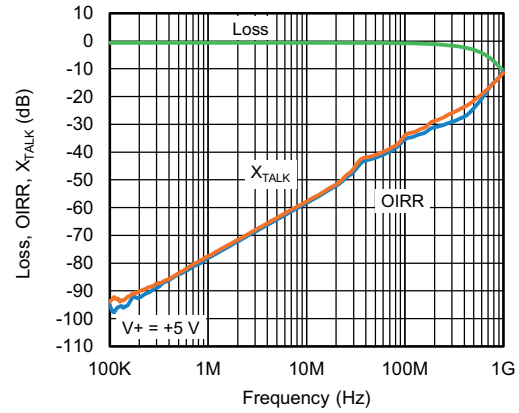

R$_{DS(on)}$ vs. Analog Voltage and Temperature

R$_{DS(on)}$ vs. Analog Voltage and Temperature

Leakage Current vs. Temperature

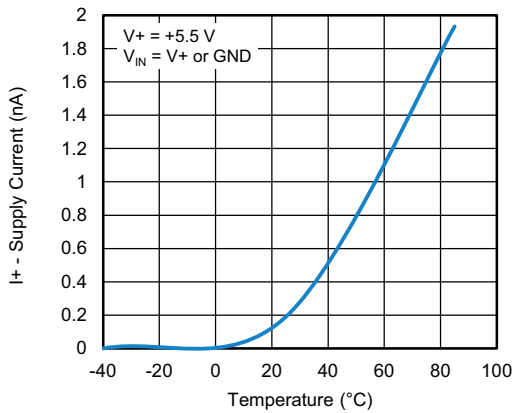For technical questions, contact: analogswitchtechsupport@vishay.com

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Leakage Current vs. Temperature

Insertion Loss, Off-Isolation Crosstalk vs. Frequency

Supply Current vs. Temperature
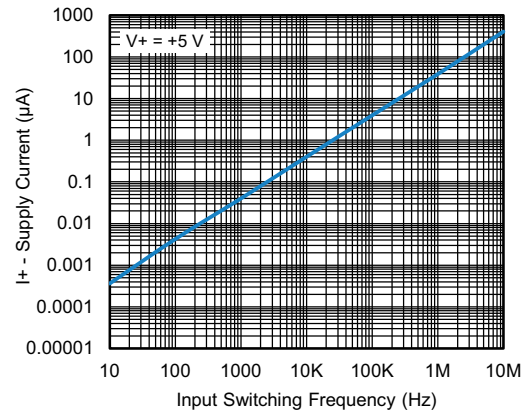
Supply Current vs. Input Switching Frequency
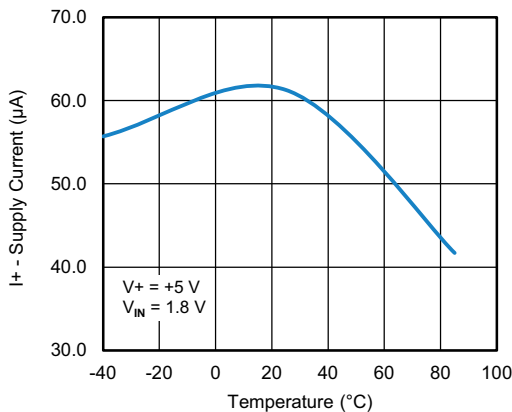
Supply Current vs. Temperature

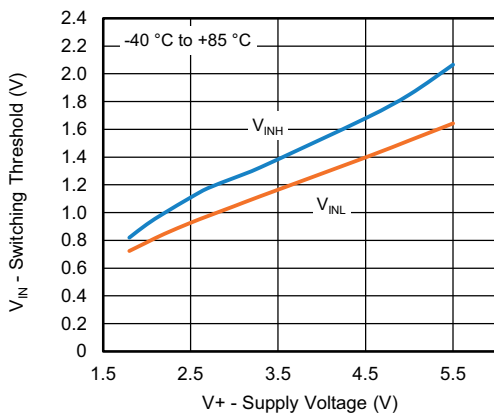**Switching Time vs. Temperature**

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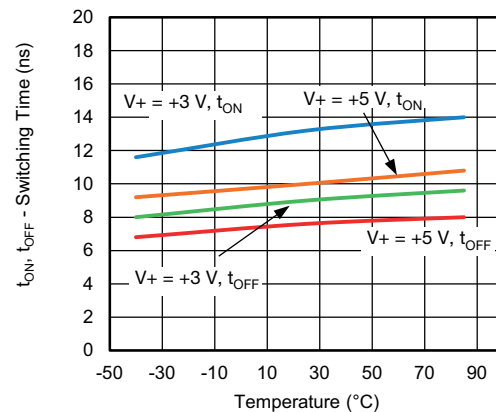
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)
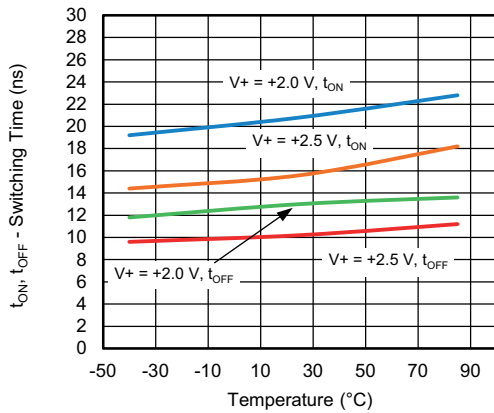
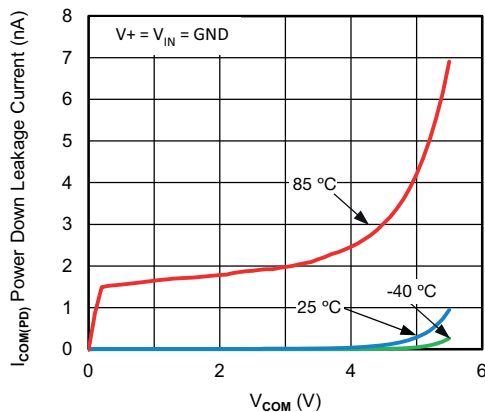**Switching Time vs. Temperature**
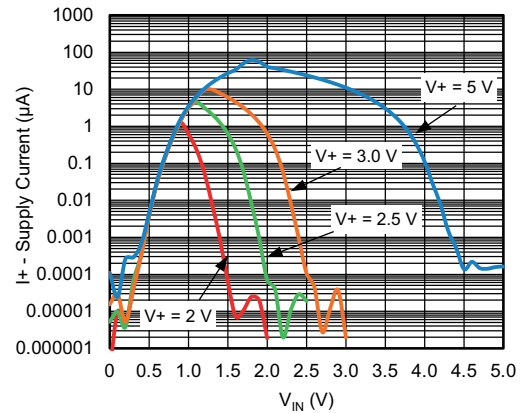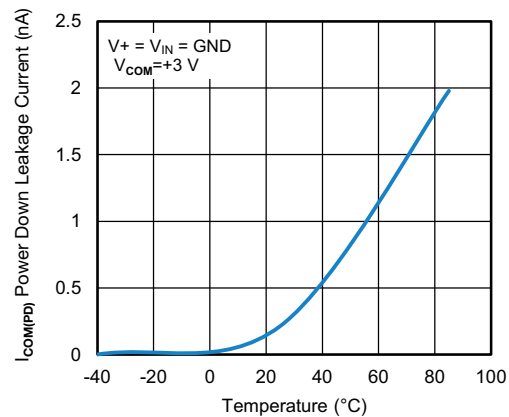

Supply Current vs. Enable Input Voltage

Switching Threshold vs. Supply Voltage
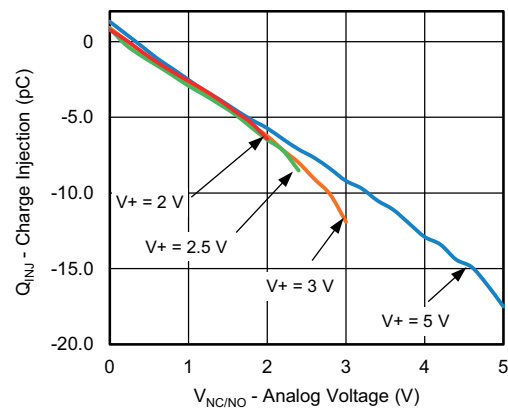
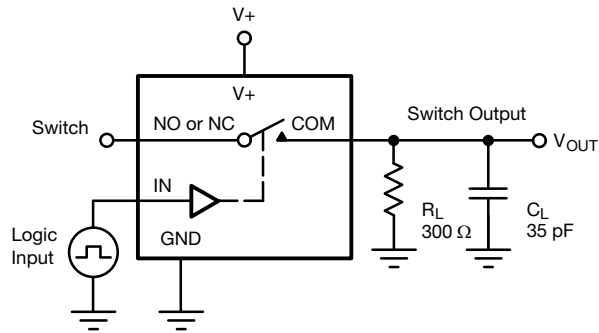**Charge Injection vs. Analog Voltage**

Power Down Leakage Current vs V_COM

Power Down Leakage Current vs Temperature
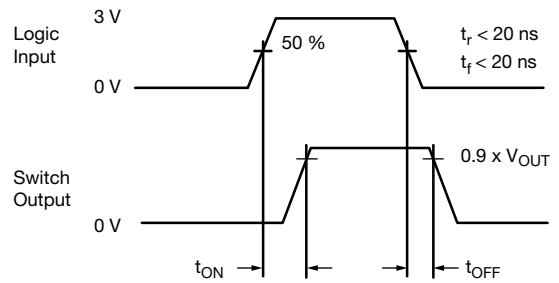
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TEST CIRCUITS

C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Fig. 1 - Switching Time

Logic "1" = switch on
Logic input waveforms inverted for switches that have the opposite logic sense.
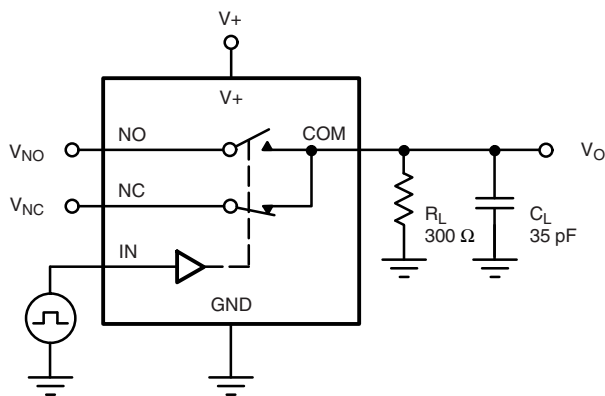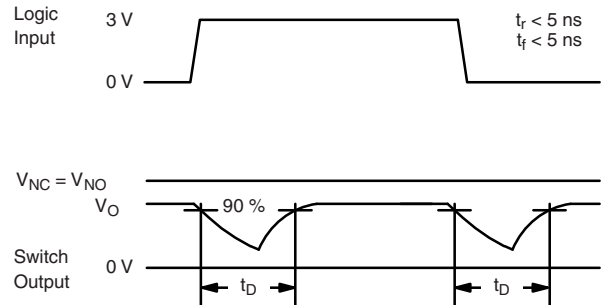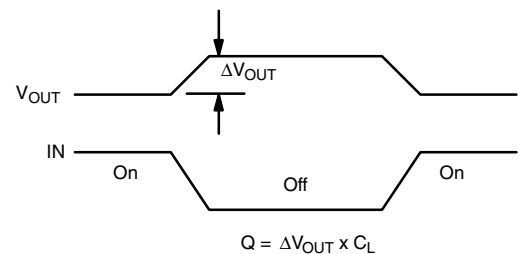

C_L (includes fixture and stray capacitance)

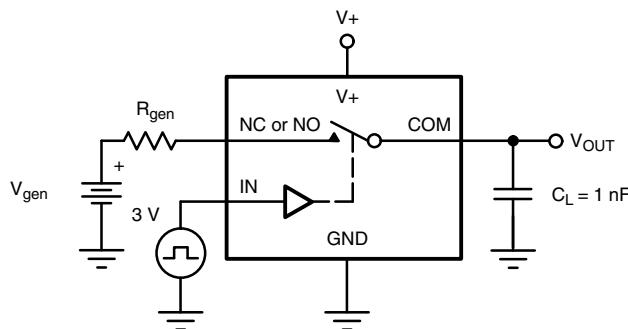**Fig. 2 - Break-Before-Make Interval**

$$Q = \Delta V_{OUT} \times C_L$$

IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection

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TEST CIRCUITS

Fig. 4 - Off-Isolation

$$\text{Off Isolation} = 20 \log \frac{V_{NC/NO}}{V_{COM}}$$
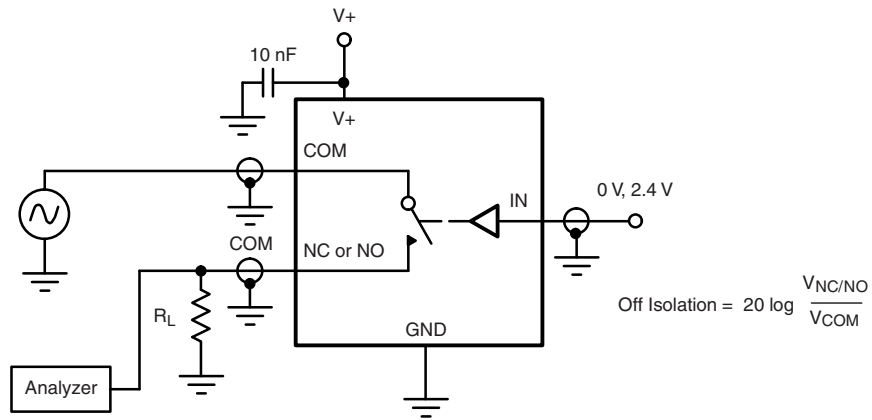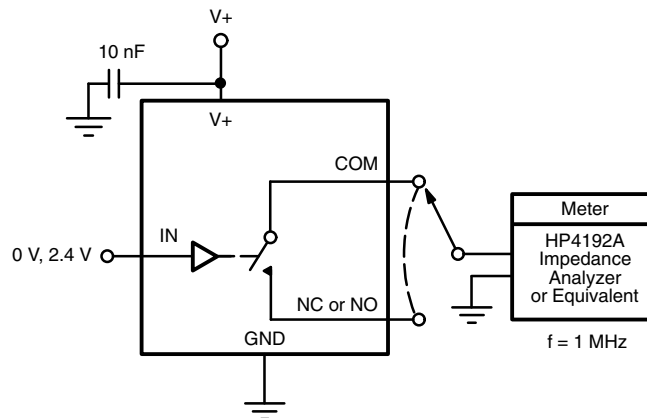
Fig. 5 - Channel Off / On Capacitance

PRODUCT SUMMARY

Part number	DG9411E
Status code	2
Configuration	SPDT x 1
Single supply min. (V)	1.8
Single supply max. (V)	5.5
Dual supply min. (V)	-
Dual supply max. (V)	-
On-resistance (Ω)	6
Charge injection (pC)	1
Source on capacitance (pF)	13
Source off capacitance (pF)	7
Leakage switch on typ. (nA)	-
Leakage switch off max. (nA)	1.5
-3 dB bandwidth (MHz)	-
Package	SC-70-6
Functional circuit / applications	Multi Purpose, instrumentation, medical and healthcare, portable
Interface	Parallel
Single supply operation	Yes
Dual supply operation	-
Turn on time max. (ns)	30
Crosstalk and off isolation	-77

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